



# **Epitaxial Planar Power Zener Diodes**

# ZMYXXXX



LL-41 (MELF) Glass Axial Package RoHS compliant

## **GENERAL DISCRIPTIONS:**

For use in stabilizing and clipping circuits with high power rating. The Zener voltages are graded according to the international E24 standard. Smaller voltage tolerances are upon request.

### ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C Unless otherwise specified)

PARAMETER	SYMBOL	VALUE	UNIT
Power Dissipation	P <sub>tot</sub>	1	W
Junction Temperature	Tj	175	°C
Storage Temperature Range	T <sub>STG</sub>	-55to +175	°C

## **Thermal Resistance**

Thermal Resistance Junction to Ambient <sup>1</sup>	R <sub>θJA</sub>	150	°C/W
Neder			

#### Note:

1. Valid provided that electrodes are kept at ambient temperature.

## ELECTRICAL CHARACTERISTICS at (Ta = 25 °C Unless otherwise specified)

Туре	Z	ener Voltage		Dynamic Resistance		Reverse Current		Admissible Zener Current
Type	V	, zт	at I <sub>z⊤</sub>	Z <sub>ZT</sub>	at I <sub>z⊤</sub>	I <sub>R</sub>	at V <sub>R</sub>	Zener ourrent
	Min. (V)	Max. (V)	(mA)	Max. (Ω)	(mA)	Max. (µA)	(V)	I <sub>zM</sub> (mA)
ZMY1 <sup>3</sup>	0.65	0.75	5	8	5			406
ZMY3V0	2.8	3.2	100	8	100			260
ZMY3V3	3.1	3.5	100	8	100	150	1	240
ZMY3V6	3.4	3.8	100	8	100	100	1	220
ZMY3V9	3.7	4.1	100	7	100	100	1	203
ZMY4V3	4	4.6	100	7	100	50	1	182
ZMY4V7	4.4	5	100	7	100	10	1	165
ZMY5V1	4.8	5.4	100	5	100	10	1	150
ZMY5V6	5.2	6	100	2	100	0.5	2	135
ZMY6V2	5.8	6.6	100	2	100	0.5	3	128
ZMY6V8	6.4	7.2	100	2	100	0.5	4	110

ZMYXXXX

Rev0 06062022EGL





Continental Device India Pvt. Limited An IATF 16949, ISO9001 and ISO 14001 Certified Company

## **ELECTRICAL CHARACTERISTICS at** (Ta = 25 °C Unless otherwise specified)

	Z	Zener Voltage			Dynamic Resistance		Current	Admissible
Туре	V	ZT	at I <sub>zT</sub>	Z <sub>ZT</sub>	at I <sub>zt</sub>	I <sub>R</sub>	at V <sub>R</sub>	Zener Current
	Min. (V)	Max. (V)	(mA)	Max. (Ω)	(mA)	Max. (µA)	(V)	I <sub>zM</sub> (mA)
ZMY7V5	7	7.9	100	2	100	0.5	5	100
ZMY8V2	7.7	8.7	100	2	100	0.5	6	89
ZMY9V1	8.5	9.6	50	4	50	0.5	7	82
ZMY10	9.4	10.6	50	4	50	0.5	7.6	74
ZMY11	10.4	11.6	50	7	50	0.5	8.4	66
ZMY12	11.4	12.7	50	7	50	0.5	9.1	60
ZMY13	12.4	14.1	50	9	50	0.5	9.9	55
ZMY15	13.8	15.8	50	9	50	0.5	11.4	49
ZMY16	15.3	17.1	25	10	25	0.5	12.2	44
ZMY18	16.8	19.1	25	11	25	0.5	13.7	40
ZMY20	18.8	21.2	25	12	25	0.5	15.2	36
ZMY22	20.8	23.3	25	13	25	0.5	16.7	34
ZMY24	22.8	25.6	25	14	25	0.5	18.2	29
ZMY27	25.1	28.9	25	15	25	0.5	20.6	27
ZMY30	28	32	25	20	25	0.5	22.8	25
ZMY33	31	35	25	20	25	0.5	25.1	22
ZMY36	34	38	10	60	10	0.5	27.4	20
ZMY39	37	41	10	60	10	0.5	29.7	18
ZMY43	40	46	10	80	10	0.5	32.7	17
ZMY47	44	50	10	80	10	0.5	35.8	15
ZMY51	48	54	10	100	10	0.5	38.8	14
ZMY56	52	60	10	100	10	0.5	42.6	13
ZMY62	58	66	10	130	10	0.5	47.1	11
ZMY68	64	72	10	130	10	0.5	51.7	10
ZMY75	70	79	10	160	10	0.5	56.0	9

Note:

2. Tested with pulses  $t_p$  = 20 ms

3. The ZMY1 is a silicon diode operated in forward direction. Hence, the index of all characteristics and maximum ratings should be "F" instead of "Z". Connect the cathode terminal to the negative pole.



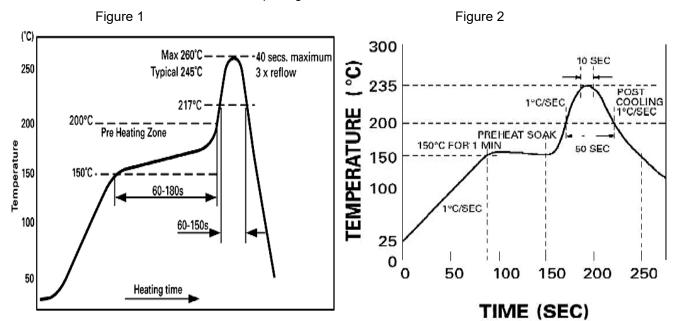


#### **Recommended Reflow Solder Profiles**

The recommended reflow solder profiles for Pb and Pb-free devices are shown below.

Figure 1 shows the recommended solder profile for devices that have Pb-free terminal plating, and where a Pb-free solder is used.

Figure 2 shows the recommended solder profile for devices with Pb-free terminal plating used with leaded solder, or for devices with leaded terminal plating used with a leaded solder.



#### Reflow profiles in tabular form

Profile Feature	Sn-Pb System	Pb-Free System
Average Ramp-Up Rate	~3°C/second	~3°C/second
<b>Preheat</b> – Temperature Range – Time	150-170°C 60-180 seconds	150-200°C 60-180 seconds
Time maintained above: – Temperature – Tim	200°C 30-50 seconds	217°C 60-150 seconds
Peak Temperature	235°C	260°C max.
Time within +0 -5°C of actual Peak	10 seconds	40 seconds
Ramp-Down Rate	3°C/second max.	6°C/second max

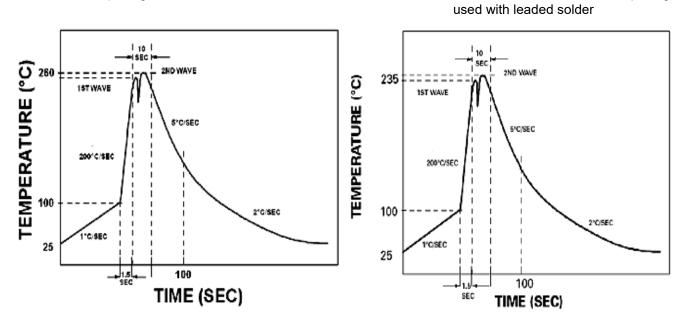




### **Recommended Wave Solder Profiles**

The Recommended solder Profile For Devices with Pb-free terminal plating where a Pb-free solder is used

The Recommended solder Profile For Devices with Pb-free terminal plating used with leaded solder, or for devices with leaded terminal plating



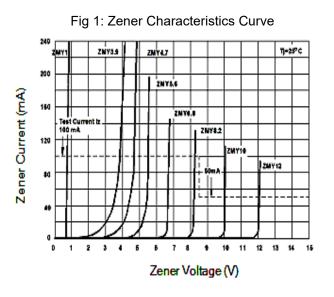
### Wave Profiles in Tabular Form

Profile Feature	Sn-Pb System	Pb-free System
Average Ramp-Up Rate	~200°C/second	~200°C/second
Heating rate during preheat	Typical 1-2, Max 4°C/sec	Typical 1-2, Max 4°C/Sec
Final preheat Temperature	Within 125°C of Solder Temp	Within 125°C of Solder Temp
Peak Temperature	235°C	260°C max.
Time within +0 -5°C of actual Peak	10 seconds	10 seconds
Ramp-Down Rate	5°C/second max.	5°C/second max.



¶=26°C

# TYPICAL CHARACTERISTICS CURVES



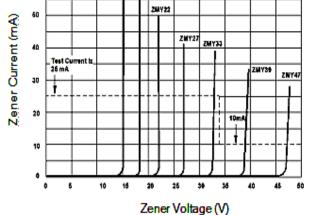
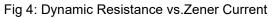


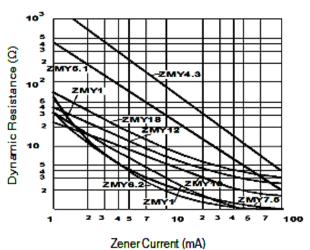
Fig 3: Zener Characteristics Curve

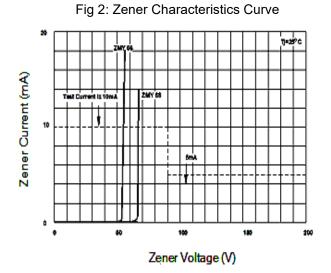
ZŃYIE

ZMY1

60









# **TYPICAL CHARACTERISTIC CURVES**

Fig 5: Dynamic Resistance vs.Zener Current

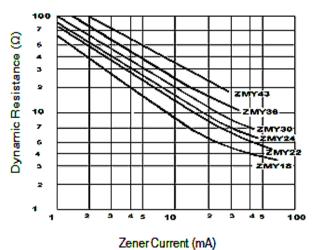


Fig 7: Dynamic Resistance vs.Zener Current

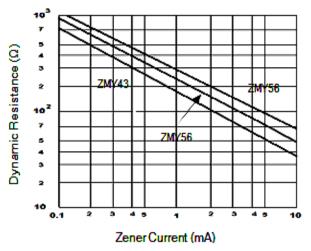


Fig 6: Power Derating Curve

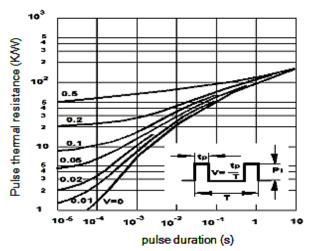
100

Ambient Temperature (°C)

150

200

Fig 8: Pulse thermal resistance vs. pulse duration



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1

0.8

0.6

0.4

0.2

0

0

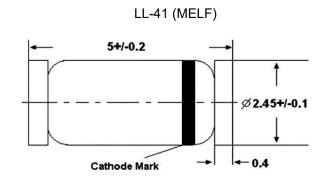
25

Power Dissipation (W)





# Package Details



Dimensions in mm





# Recommended Product Storage Environment for Discrete Semiconductor Devices

This storage environment assumes that the Diodes and transistors are packed properly inside the original packing supplied by CDIL.

- · Temperature 5 °C to 30 °C
- · Humidity between 40 to 70 %RH
- · Air should be clean.
- · Avoid harmful gas or dust.
- $\cdot$  Avoid outdoor exposure or storage in areas subject to rain or water spraying .
- · Avoid storage in areas subject to corrosive gas or dust. Product shall not be stored in areas exposed to direct sunlight.
- · Avoid rapid change of temperature.
- · Avoid condensation.
- · Mechanical stress such as vibration and impact shall be avoided.
- · The product shall not be placed directly on the floor.
- The product shall be stored on a plane area. They should not be turned upside down. They should not be placed against the wall.

#### Shelf Life of CDIL Products

The shelf life of products is the period from product manufacture to shipment to customers. The product can be unconditionally shipped within this period. The period is defined as 2 years.

If products are stored longer than the shelf life of 2 years the products shall be subjected to quality check as per CDIL quality procedure.

The products are further warranted for another one year after the date of shipment subject to the above conditions in CDIL original packing.

#### Floor Life of CDIL Products and MSL Level

When the products are opened from the original packing, the floor life will start. For this, the following JEDEC table may be referred:

JEDEC MSL Level				
Level	Time	Condition		
1	Unlimited	≤30 °C / 85% RH		
2	1 Year	≤30 °C / 60% RH		
2a	4 Weeks	≤30 °C / 60% RH		
3	168 Hours	≤30 °C / 60% RH		
4	72 Hours	≤30 °C / 60% RH		
5	48 Hours	≤30 °C / 60% RH		
5a	24 Hours	≤30 °C / 60% RH		
6	Time on Label(TOL)	≤30 °C / 60% RH		





## **Customer Notes**

### **Component Disposal Instructions**

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

## Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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